

BiS₂ - based superconductivity in F-substituted NdOBiS₂

Satoshi Demura,^{1,2} Yoshikazu Mizuguchi,^{1,3} Keita Deguchi,^{1,2} Hiroyuki Okazaki,¹

Hiroshi Hara,^{1,2} Tohru Watanabe,^{1,2} Saleem James Denholme,¹ Masaya Fujioka,¹

Toshinori Ozaki,¹ Hiroshi Fujihisa,⁴ Yoshito Gotoh,⁴ Osuke Miura,³ Takahide Yamaguchi,¹

Hiroyuki Takeya,¹ and Yoshihiko Takano^{1,2}

E-mail : Demura.Satoshi@nims.go.jp

¹National Institute for Materials Science, 1-2-1 Sengen, Tsukuba, Ibaraki 305-0047, Japan

²University of Tsukuba, Graduate School of Pure and Applied Sciences, Tsukuba, Ibaraki 305-8577, Japan

³Tokyo Metropolitan University, Graduate School of Science and Engineering, Hachioji, Tokyo 192-0397, Japan

⁴National Institute of Advanced Industrial Science and Technology (AIST), Tsukuba Central 5, 1-1-1, Higashi, Tsukuba 305-8565, Japan.

Abstract

We have successfully synthesized a new BiS₂-based superconductor NdOBiS₂ with F-doping. This compound is composed of superconducting BiS₂ layers and blocking NdO layers, which indicates that the BiS₂ layer is the one of the common superconducting layers like the CuO₂ layer of cuprates or Fe-As layer of Fe-based superconductors. We can obtain

$\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ with bulk superconductivity by a solid-state reaction under ambient pressure.

Therefore, $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ should be the suitable material to elucidate the mechanism of superconductivity in the BiS_2 -layer.

Quite recently, Y. Mizuguchi et al. reported superconductivity in the novel BiS₂-based superconductor Bi₄O₄S₃ with a superconducting transition temperature (T_c) of 8.6 K [1]. This material has a layered structure composed of superconducting BiS₂ layers and blocking layers of Bi₄O₄(SO₄)_{1-x}, where x indicates the defects of SO₄²⁻ ions at the interlayer sites. The stacking structure of the superconducting and blocking layer is analogous to those of high- T_c cuprates [2-5] and Fe-based superconductors [6-14]. In both systems, their T_c can be enhanced by changing the blocking layers. In order to enhance the T_c of the BiS₂-based superconductor, the investigation of exchanging the blocking layer will be of great interest.

Soon after the discovery of Bi₄O₄S₃, a new BiS₂-based superconductor LaO_{1-x}F_xBiS₂ was reported [15]. This compound consists of the same superconducting layer but with different blocking layers compared to that of Bi₄O₄S₃. Furthermore, the superconductivity shows a relatively high T_c of 10.6 K. This fact suggests that the BiS₂ layer is the common superconducting layer, and the blocking layer contributes to the enhancement of the T_c in this system. LaO_{1-x}F_xBiS₂ shows a small superconducting volume fraction for ambient pressure but achieves bulk superconductivity under high pressure. This result suggests that high pressure would promote F substitution. Therefore, chemical pressure for the exchange of La by Nd possibly induces the promotion of F substitution. Here, we report that a new BiS₂-based superconductor NdO_{1-x}F_xBiS₂ ($x = 0.1 - 0.7$) can be obtained by a solid-state reaction under ambient pressure.

The polycrystalline samples of $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$) were prepared by a solid-state reaction. Mixtures of Bi grains, Bi_2S_3 grains, Nd_2O_3 powders, Nd_2S_3 powders, and NdF_3 powders with nominal compositions of $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$) were ground, pelletized, and sealed into an evacuated quartz tube. The tube was heated at $800\text{ }^\circ\text{C}$ for 10 h. The obtained samples were characterized by X-ray diffraction with $\text{Cu-K}\alpha$ radiation using the θ - 2θ method. The temperature dependence of magnetization was measured by a superconducting quantum interface device (SQUID) magnetometer with an applied field of 1 Oe. The resistivity measurements were performed using the four-terminal method from 300 to 2 K. In order to investigate an upper critical field of $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$, the temperature dependence of resistivity between 10 and 2 K was measured under a magnetic field of up to 7 T.

Figure 1(a) shows the X-ray diffraction profile for the powdered samples of $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$). With the exception of a few minor peaks relating to impurity phases, all of the peaks can be characterized to space group $P4/nmm$. The nominal x dependence of the lattice constants a and c is summarized in Fig. 1(b) and (c). These lattice constants were estimated from 2θ values and Miller indices. The a lattice constant exhibits little change with increasing x while the c lattice constant dramatically decreases. The decrease of the lattice parameter c indicates that F substitutes O since the ionic radius of F is smaller than that of O.

Figure 2(a) shows the temperature dependence of magnetic susceptibility for $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$). A superconducting transition is observed for all samples. These samples with $x = 0.1 - 0.6$ exhibit a high shielding volume fraction exceeding 90 % (2 K, ZFC), indicating the appearance of bulk superconductivity in those samples. The x dependence of T_c is plotted in Fig. 2(b). The T_c varies like a bell curve with increasing x . The $\text{NdO}_{0.7}\text{F}_{0.3}\text{BiS}_2$ sample exhibits the optimal T_c of all samples.

The temperature dependence of the resistivity for $\text{NdO}_{0.7}\text{F}_{0.3}\text{BiS}_2$ is shown in Fig. 3. Resistivity slightly decreases between 300 and 130 K. Below 130 K, resistivity gradually increases and the superconducting transition appears around 6 K. This behavior, where the resistivity increases with decreasing temperature is also observed in $\text{LaO}_{1-x}\text{F}_x\text{BiS}_2$. The onset and zero-resistivity temperatures are estimated to be $T_c^{\text{onset}} = 5.6$ K and $T_c^{\text{zero}} = 5.2$ K, respectively. Figure 4(a) shows the temperature dependence of the resistivity from 10 to 2 K under a magnetic field. The T_c of $\text{NdO}_{0.7}\text{F}_{0.3}\text{BiS}_2$ decreases with increasing magnetic field. The upper critical field (B_{c2}) and the irreversibility field (B_{irr}) are plotted in Fig. 4(b). The $B_{c2}(0)$ was estimated to be 5.2 T with the data points at 0.4 ~ 2.0 T using the WHH theory, which gives $B_{c2}(0) = -0.69T_c(d B_{c2}/dT)|_{T_c}$ [16].

In conclusion, the BiS_2 -based superconductor $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$) has been successfully synthesized by a solid-state reaction method. Chemical pressure promotes the F substitution, which originated from the exchange of La by Nd. As a result, $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ with

bulk superconductivity can be obtained under ambient pressure. These results demonstrate that the BiS₂ layer is the common superconducting layer. Thus, if we synthesize materials with the stacking structure consisting of the BiS₂ layer and other blocking layers, new superconductors with the BiS₂-layer would be discovered.

Acknowledgements

This work was partly supported by a Grant-in-Aid for Scientific Research from the Ministry of Education, Culture, Sports, Science and Technology (KAKENHI).

References

- ¹ Y. Mizuguchi et al., arXiv:1207.3145.
- ² J. G. Bednorz and K. Müller, *Z. Physik B Condensed Matter* **64**, 189-193 (1986).
- ³ M. K. Wu, et al., *Phys. Rev. Lett.* **58**, 908–910 (1987).
- ⁴ H. Maeda et al., *Jpn. J. Appl. Phys.* **27**, L209-L210 (1988).
- ⁵ A. Schilling et al., *Nature* **363**, 56 - 58 (1993).
- ⁶ Y. Kamihara et al., *J. Am. Chem. Soc.* **130**, 3296–3297 (2008).
- ⁷ X. H. Chen et al., *Nature* **453**, 761-762 (2008).
- ⁸ Z. A. Ren et al., *Chinese Phys. Lett.* **25**, 2215 (2008).
- ⁹ M. Rotter, M. Tegel and D. Johrendt, *Phys. Rev. Lett.* **101**, 107006(1-4) (2008).
- ¹⁰ X. C. Wang et al., *Solid State Commun.* **148**, 538–540 (2008).
- ¹¹ F. C. Hsu et al., **105**, 14262–14264 (2008).
- ¹² K. W. Yeh et al., *EPL* **84**, 37002(p1-4) (2008).
- ¹³ Y. Mizuguchi et al. *Appl. Phys. Lett.* **94**, 012503(1-3) (2009).
- ¹⁴ J. Guo et al., *Phys. Rev. B* **82**, 180520(1-4) (2010).
- ¹⁵ Y. Mizuguchi et al., arXiv:1207.3567
- ¹⁶ N. R. Werthamer, E. Helfand, and P. C. Hohenberg, *Phys. Rev.* **147**, 295-302 (1966).

Figure caption

Fig. 1

(a) X-ray diffraction patterns of $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$). Filled circles indicate the peaks of the impurity phases. (b) and (c) show the nominal x dependence of the lattice constants a and c , respectively.

Fig. 2

(a) The temperature dependence of the magnetic susceptibility for $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$).

(b) The F concentration dependence of the superconducting transition temperature for $\text{NdO}_{1-x}\text{F}_x\text{BiS}_2$ ($x = 0.1 - 0.7$).

Fig. 3

The temperature dependence of resistivity for $\text{NdO}_{0.7}\text{F}_{0.3}\text{BiS}_2$ between 300 and 2 K.

Fig. 4

(a) The temperature dependence of the resistivity from 10 to 2 K under magnetic fields

(b) Magnetic field – temperature phase diagram for $\text{NdO}_{0.7}\text{F}_{0.3}\text{BiS}_2$. The dashed lines are linear fits to the data.

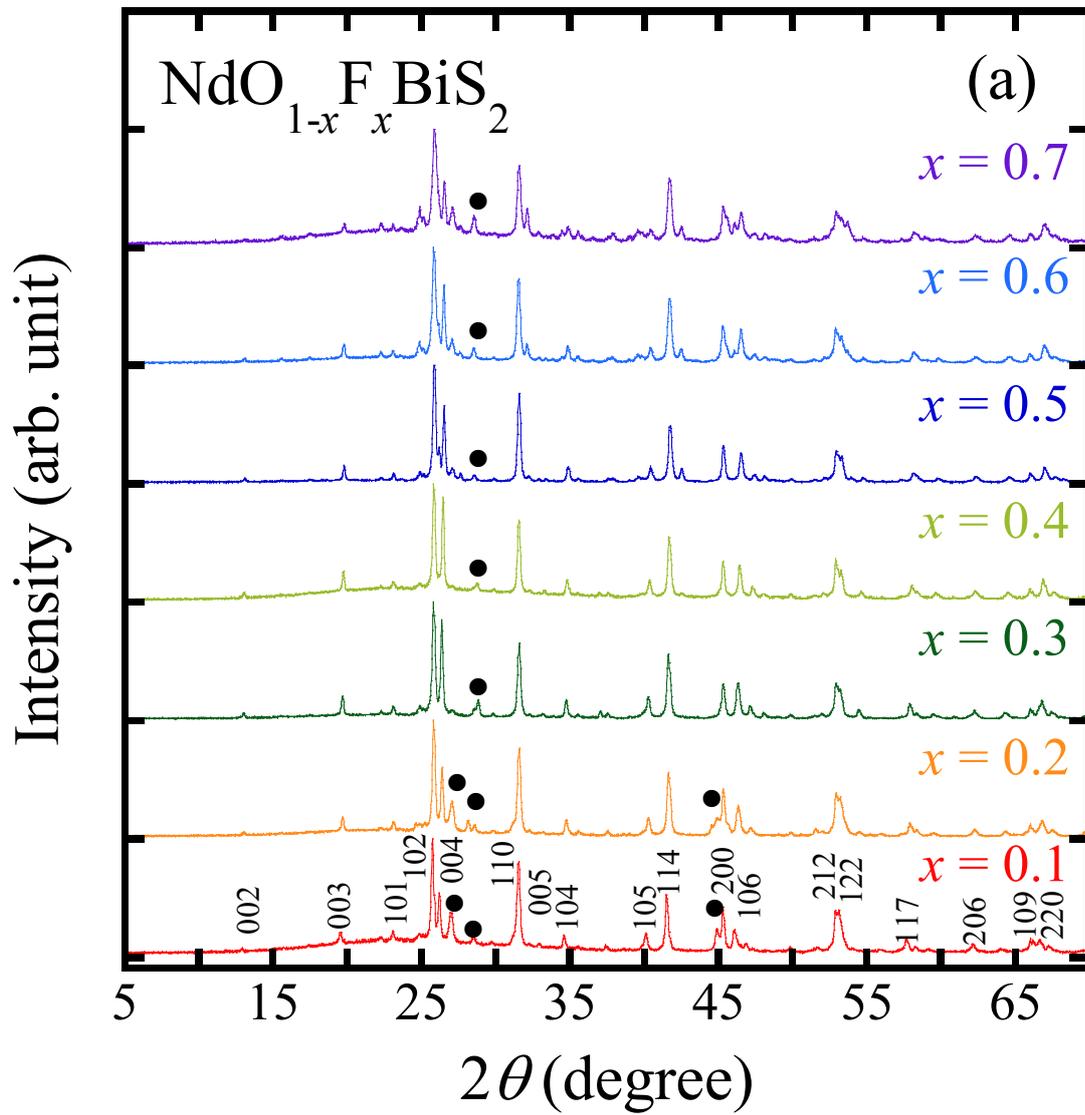


Fig. 1(a). S. Demura

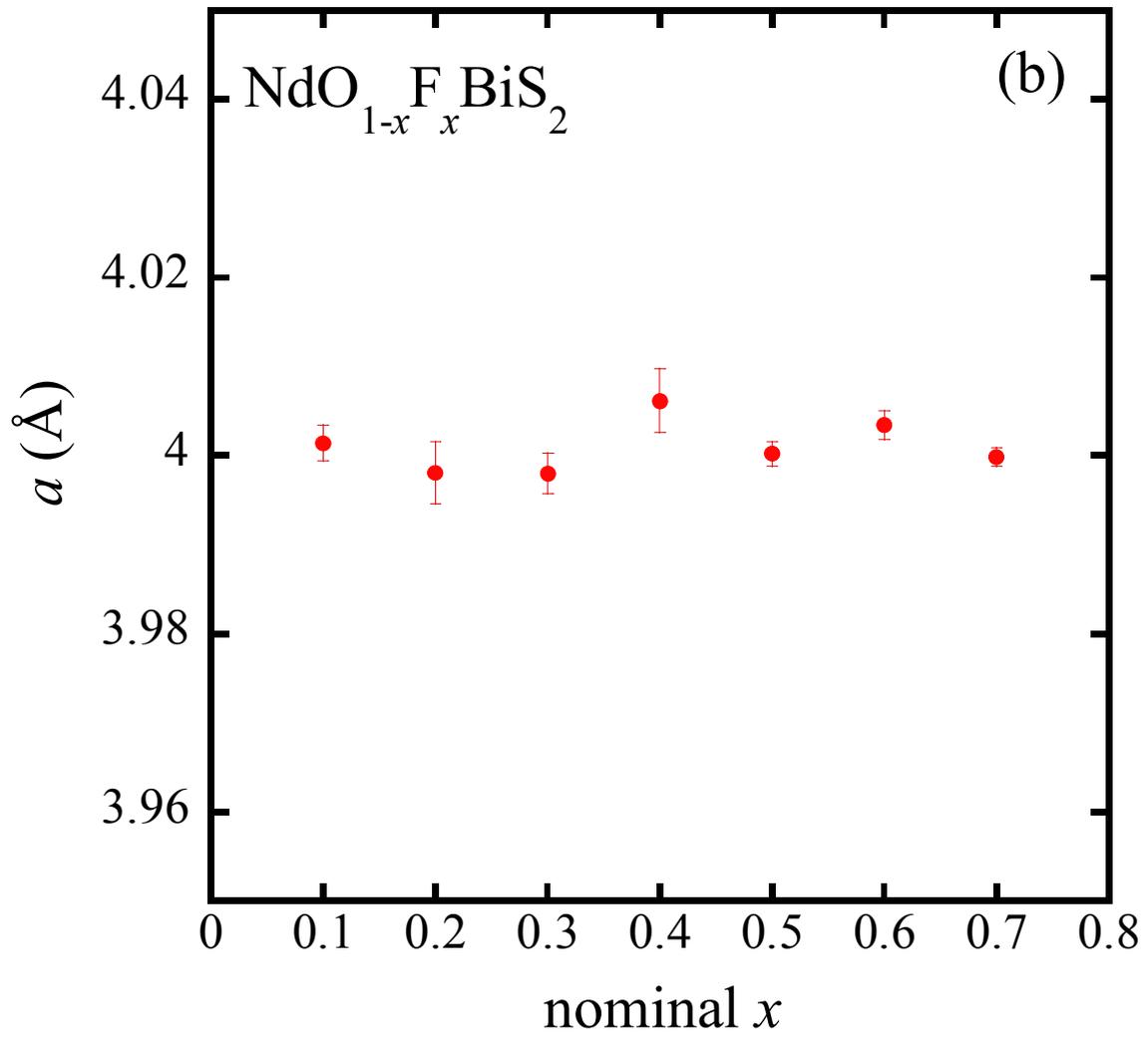


Fig. 1(b). S. Demura

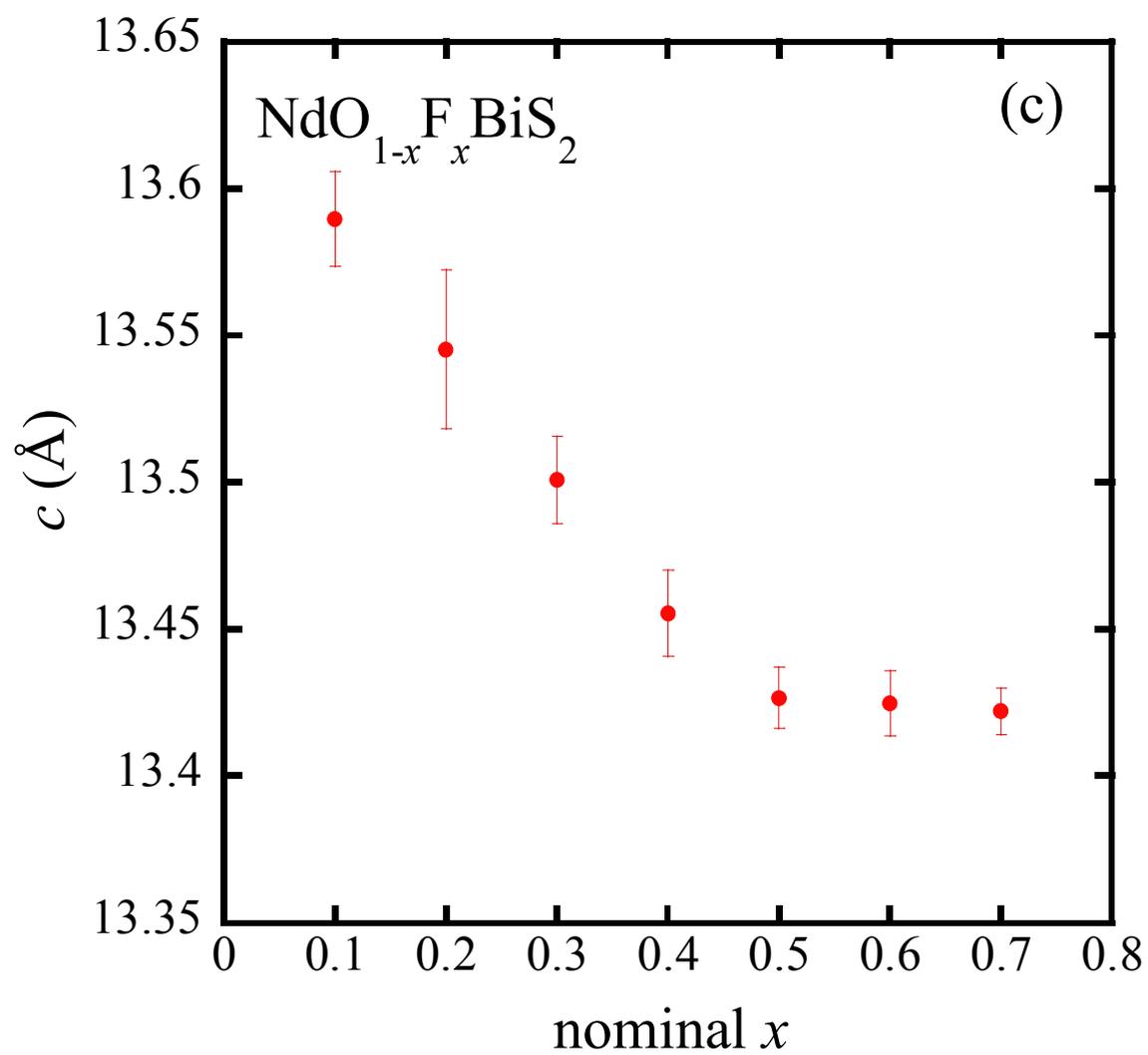


Fig. 1(c). S. Demura

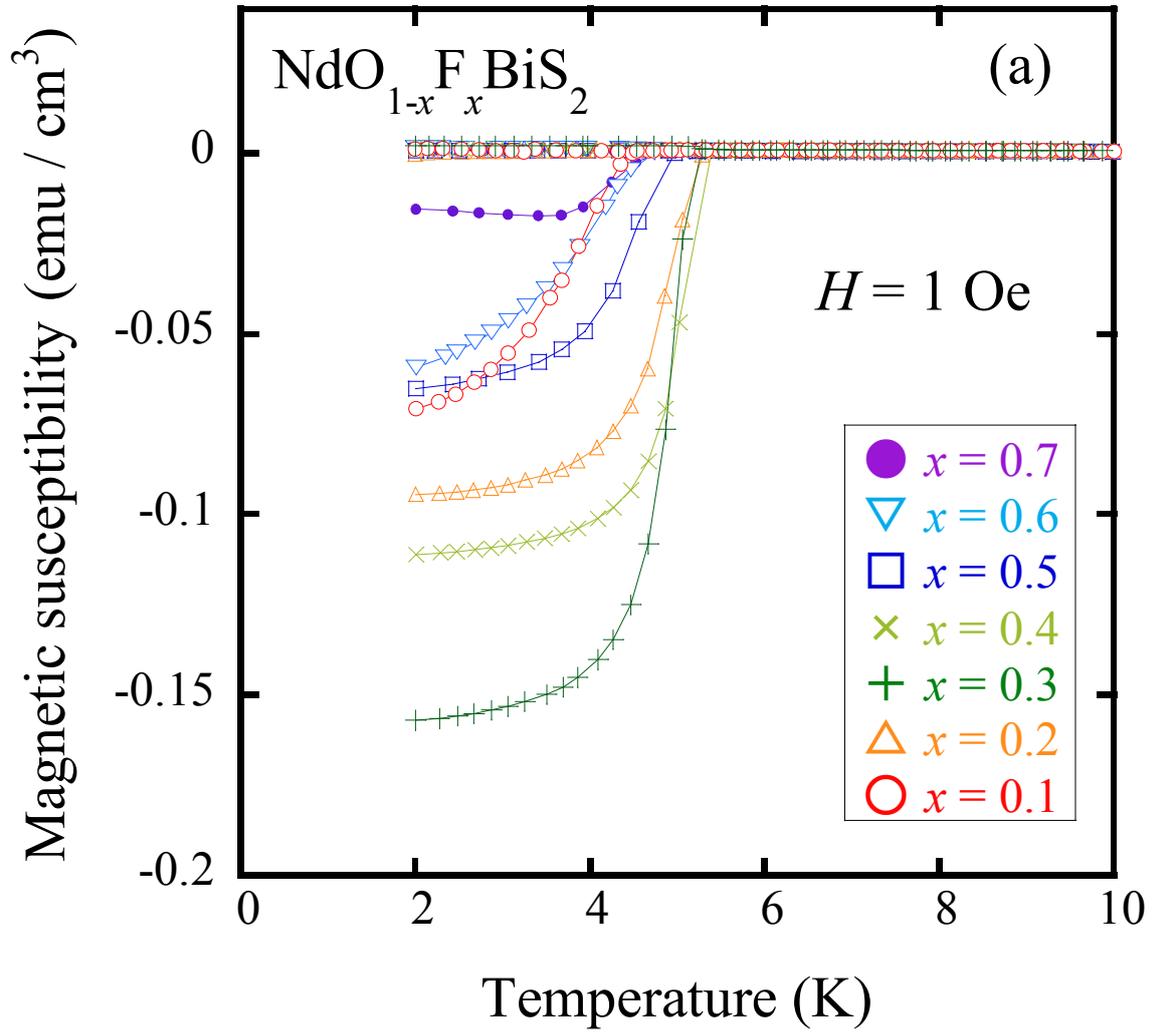


Fig. 2(a) S. Demura

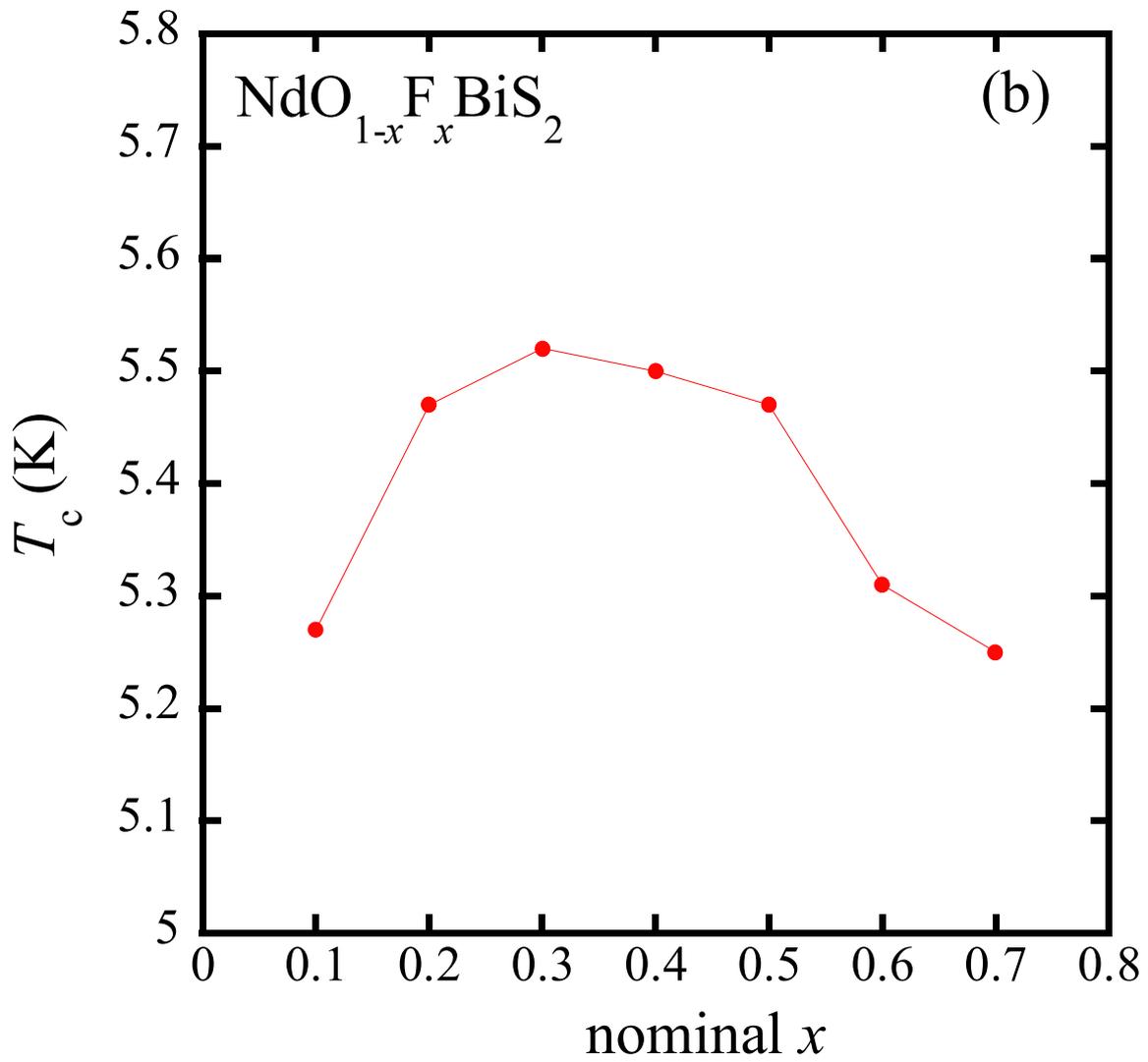


Fig. 2(b) S.Demura

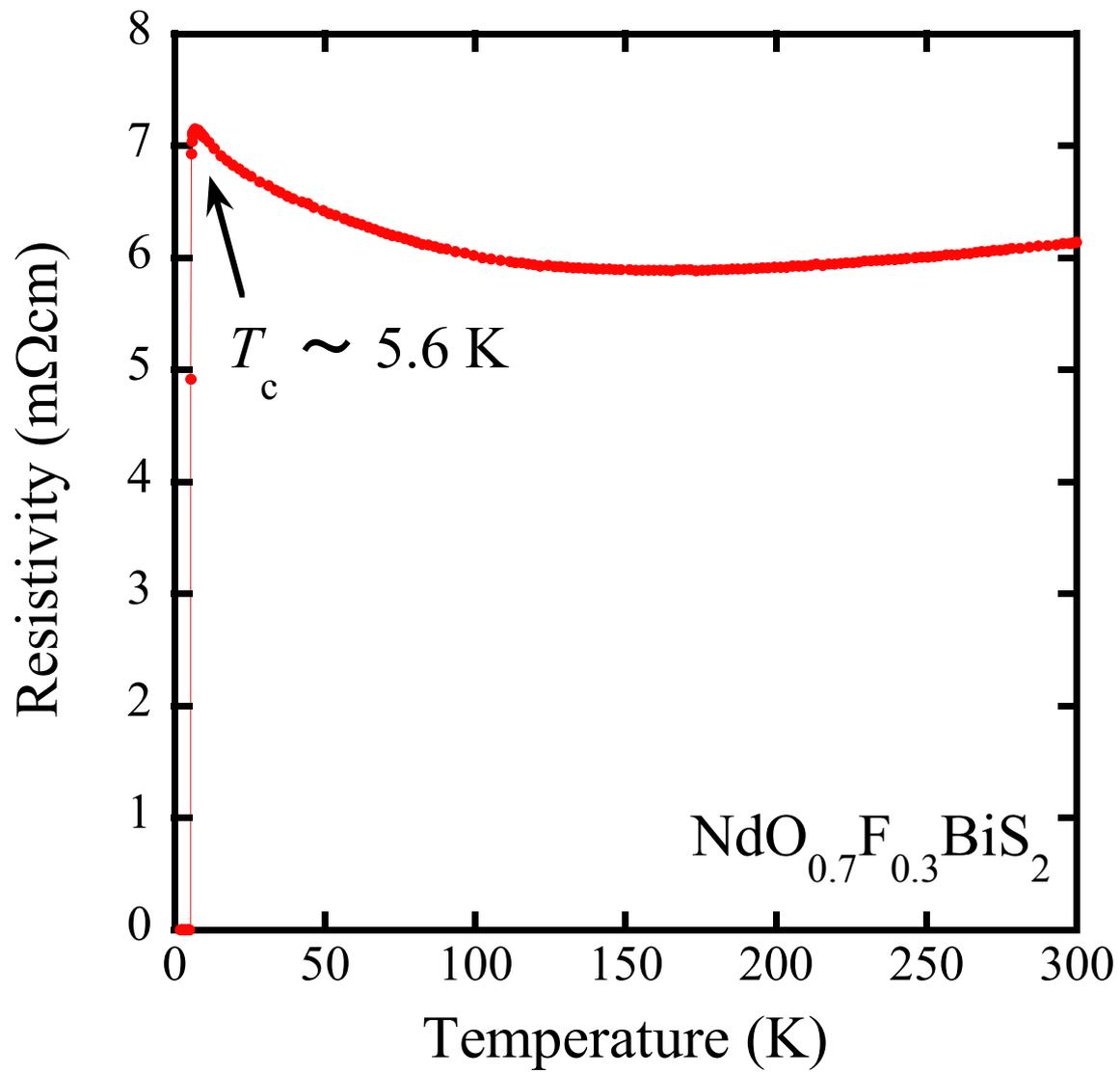


Fig. 3 S. Demura

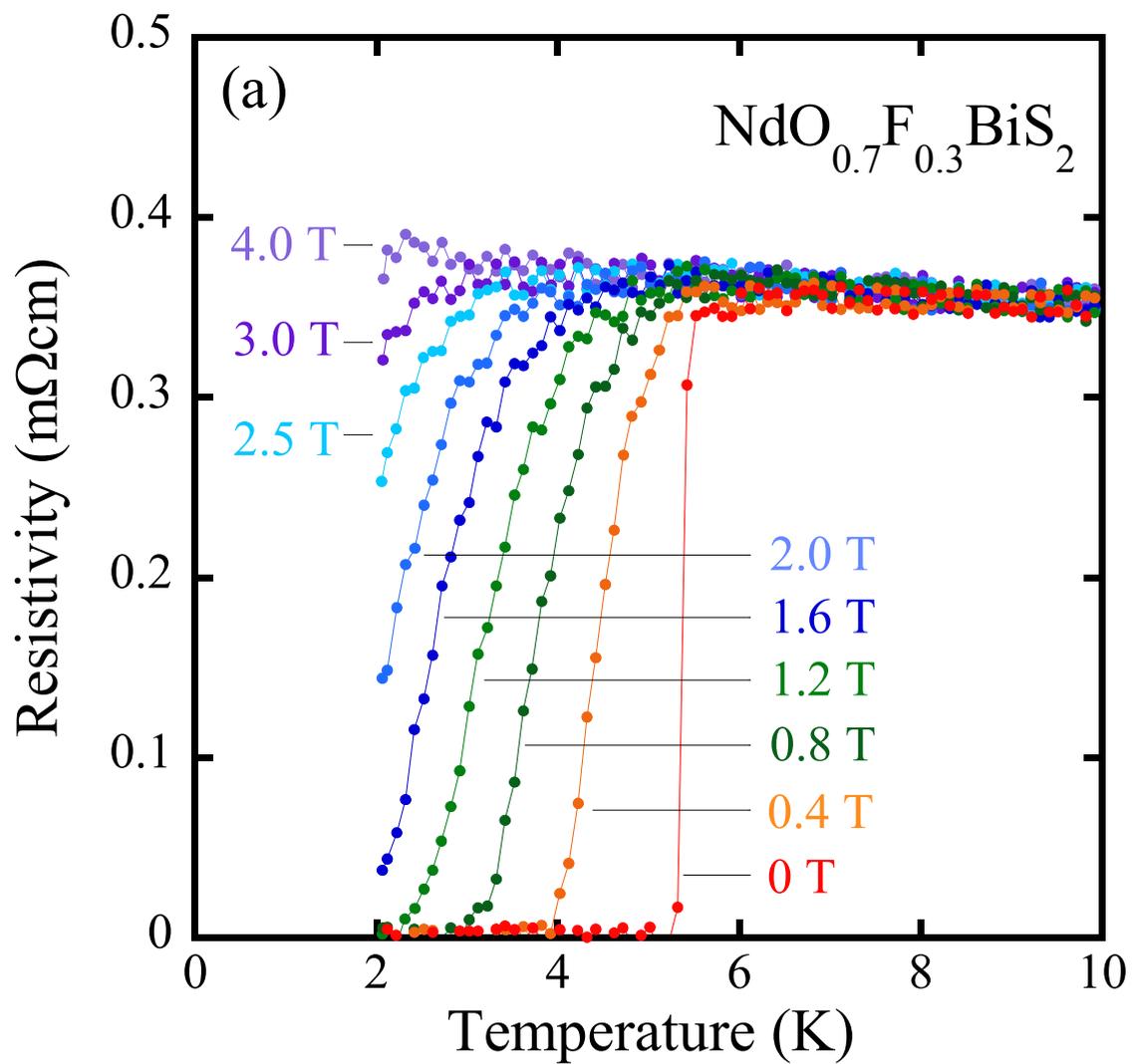


Fig. 4 S. Demura

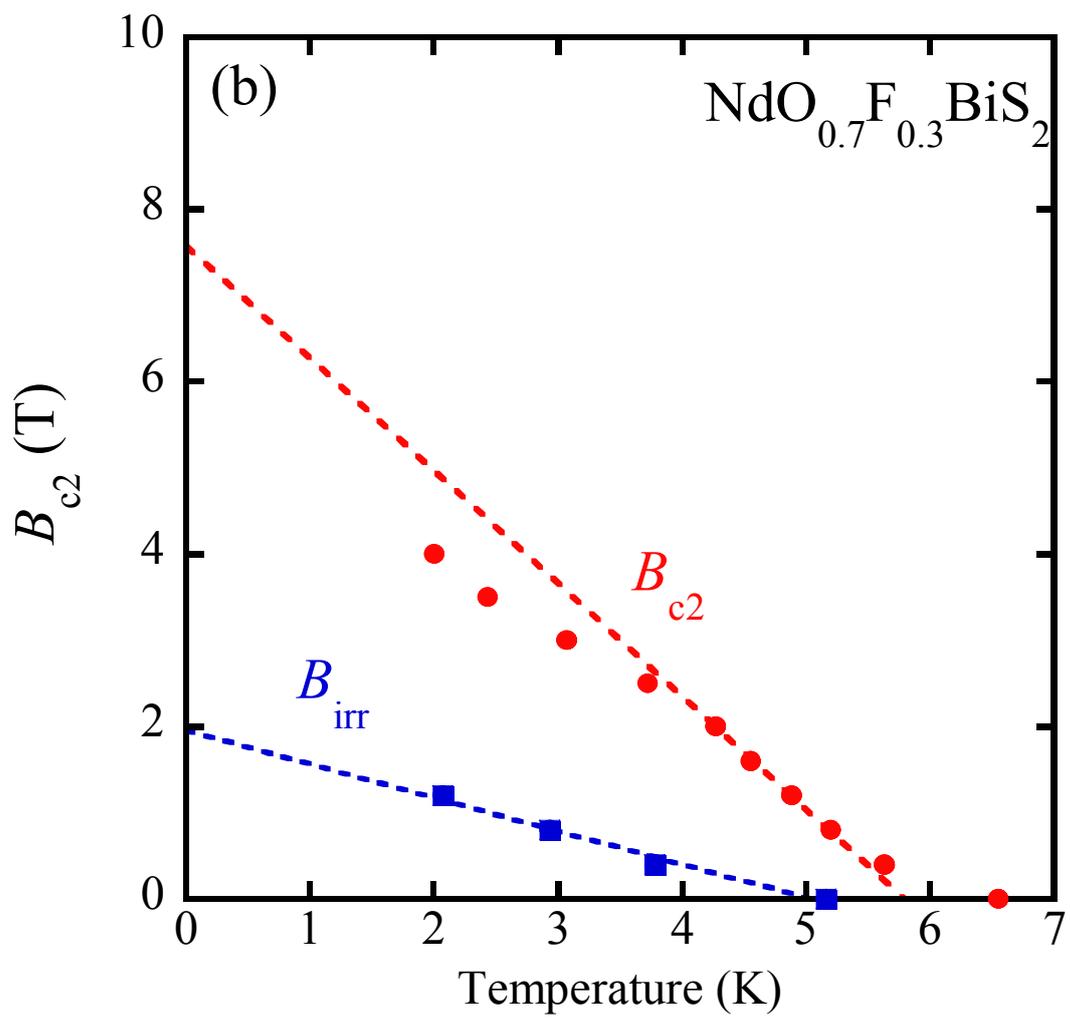


Fig. 4(b) S. Demura